# Vishay Siliconix



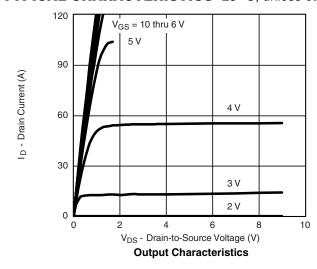
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted									
Parameter	Symbol	Test Conditions	onditions Min.		Max.	Unit			
Parameter Symbol Test Conditions Min. Typ. <sup>a</sup> Max. Unit Static									
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ 30				V			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	v			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ			
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			50				
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α			
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0076	0.0095	Ω			
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}, T_J = 125 ^{\circ}\text{C}$			0.015				
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0115	0.014				
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 20 A	20			S			
Dynamic <sup>a</sup>									
Input Capacitance	C <sub>iss</sub>			2200		pF			
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		410					
Reverse Transfer Capacitance	C <sub>rss</sub>			180					
Total Gate Charge <sup>c</sup>	Qg			11	16				
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 50 \text{ A}$		7.5		nC			
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			5.0					
Gate Resistance	$R_g$		0.5	1.5	2.1	Ω			
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			9	15				
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 0.3 $\Omega$		15	25	ns			
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 50 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		22	35				
Fall Time <sup>c</sup>	t <sub>f</sub>			8	12				
Source-Drain Diode Ratings and Characteristic T <sub>C</sub> = 25 °C									
Pulsed Current	I <sub>SM</sub>				100	Α			
Diode Forward Voltage <sup>b</sup>	$V_{SD}$	$I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}$		1.2	1.5	V			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 50 A, di/dt = 100 A/μs		35	70	ns			

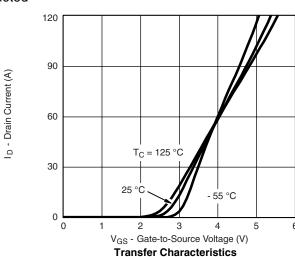
#### Notes:

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

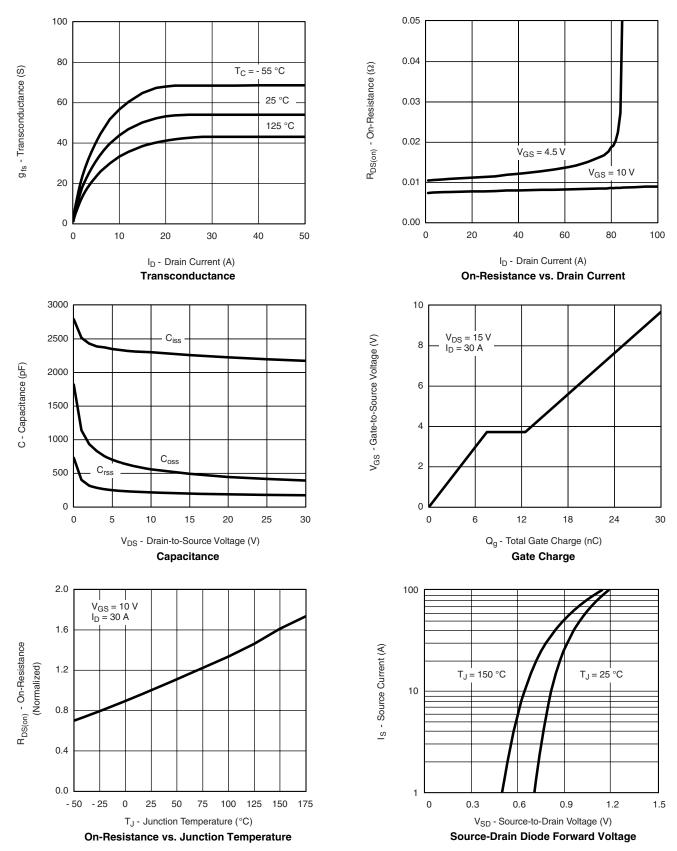
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







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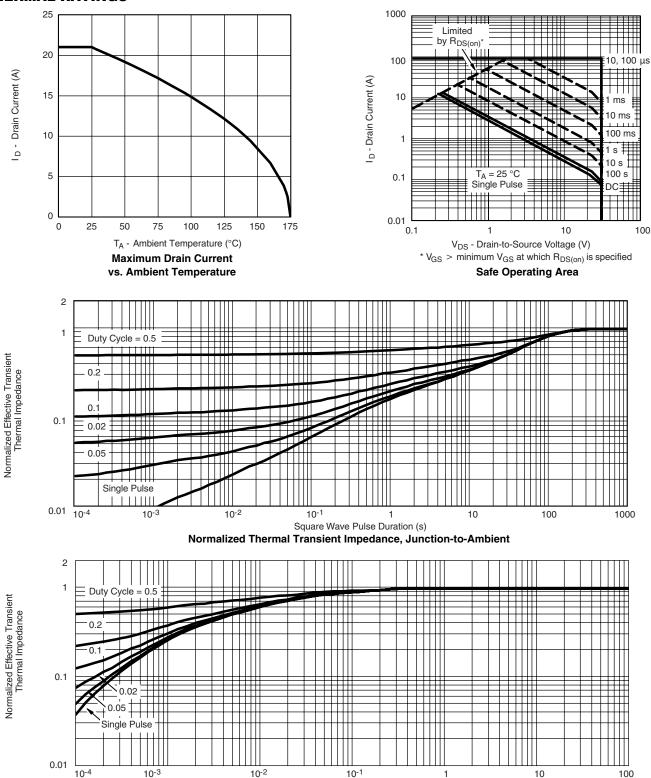


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## Vishay Siliconix

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#### THERMAL RATINGS



Square Wave Pulse Duration (s)

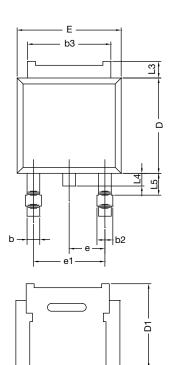
Normalized Thermal Transient Impedance, Junction-to-Case

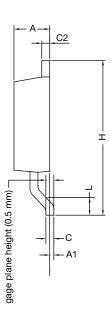
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?71856">http://www.vishay.com/ppg?71856</a>.



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## **TO-252AA Case Outline**





	MILLIMETERS		INCHES				
DIM.	MIN.	MAX.	MIN.	MAX.			
Α	2.18	2.38	0.086	0.094			
A1	-	0.127	-	0.005			
b	0.64	0.88	0.025	0.035			
b2	0.76	1.14	0.030	0.045			
b3	4.95	5.46	0.195	0.215			
С	0.46	0.61	0.018	0.024			
C2	0.46	0.89	0.018	0.035			
D	5.97	6.22	0.235	0.245			
D1	4.10	-	0.161	-			
Е	6.35	6.73	0.250	0.265			
E1	4.32	-	0.170	-			
Н	9.40	10.41	0.370	0.410			
е	2.28 BSC		0.090 BSC				
e1	4.56 BSC		0.180 BSC				
L	1.40	1.78	0.055	0.070			
L3	0.89	1.27	0.035	0.050			
L4	-	1.02	-	0.040			
L5	1.01	1.52	0.040	0.060			
ECN: T16-0236-Rev. P, 16-May-16							

ECN: T16-0236-Rev. P, 16-May-1 DWG: 5347

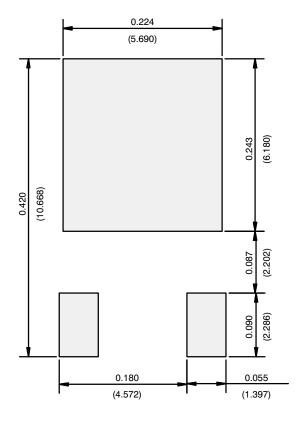
#### Notes

• Dimension L3 is for reference only.

Revision: 16-May-16 1 Document Number: 71197



## **RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)**



Recommended Minimum Pads Dimensions in Inches/(mm)

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